NSN 5961-01-185-7407

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-185-7407 **Inclosure Material:** Metal **Overall Length:** Between 2.250 inches and 2.300 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** Between 1.218 inches and 1.250 inches **Thread Size:** 0.750 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 480.0 reverse voltage, instantaneous and 400.0 working peak reverse voltage, peak total value **Current Rating Per Characteristic:** 175.00 amperes forward current, total rms megahertz **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius case **Nuclear Hardness Critical Feature:** Hardened **Terminal Type And Quantity:** 1 tab, solder lug and 1 uninsulated wire lead w/terminal lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No